

Docket No.: M4065.0697/P697-A

(PATENT)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Examiner: Jennifer M. Dolan

John T. Moore, et al.

Application No.: 10/774,515

Allowed: June 6, 2005

Filed: February 10, 2004

Art Unit: 2813

For: METHODS OF FORMING A

SEMICONDUCTOR MEMORY

**DEVICE** 

## COMMENTS ON EXAMINER'S STATEMENT OF REASONS FOR ALLOWANCE

Commissioner for Patents

MS: <u>Issue Fee</u> P.O. Box 1450

Alexandria, VA 22313-1450

Dear Sir:

Applicants agree only in part with the Examiner's statement for allowance. The Examiner's statement does not reflect all of the language of each of the allowed claims. The totality of the language of each claim provides additional reasons for the allowance of each claim.

Moreover, the Examiner's reasons for allowance are *not* commensurate in scope with all of the allowed claims. For example, the Examiner indicates that the primary reason for allowance is that the prior art fails to teach, *inter alia*, "disposing a chalcogenide material over a metal layer, diffusing a portion of the metal layer into the chalcogenide material, and then removing the portion of the chalcogenide that does not contain metal ions diffused therein. The prior art of record provides no suggestion of a

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localized doping of the chalcogenide or that any portion of the chalcogenide would remain undoped." These claim limitations, however, are not present in any of the allowed claims.

For example, claim 51 recites a method comprising, *inter alia*, "forming a metal over a substrate . . . patterning said metal into a structure having an outer surface. blanket depositing a chalcogenide material . . . on said metal structure outer surface; diffusing a portion of said patterned metal outwardly into a portion of said chalcogenide material; and etching a portion of said chalcogenide material into which said patterned metal has not been diffused."

Claim 64 recites a method comprising, *inter alia*, "forming a patterned metal structure having an outer surface . . . blanket depositing a chalcogenide material on said patterned metal structure outer surface; diffusing a portion of said patterned metal outwardly into a portion of said chalcogenide material; and etching a portion of said chalcogenide material into which said patterned metal has not been diffused."

Claim 71 recites a method comprising, *inter alia*, "forming a first electrode . . . forming a metal layer over said first electrode; forming a layer comprising a chalcogenide material . . . irradiating said metal layer to diffuse at least a portion of metal ions from said metal layer into portions of said chalcogenide layer, wherein said chalcogenide layer comprises a first region with metal ions diffused therein and a second region without a substantial amount of metal ions diffused therein; removing said second region of said chalcogenide layer . . . and forming a second electrode over at least a portion of said remaining first region of said chalcogenide layer."

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Claim 72 recites a method comprising, *inter alia*, "forming a first metal layer . . . forming a second metal layer . . . forming a chalcogenide layer . . . diffusing a portion of said second metal layer into a portion of said chalcogenide material to form a first and second region, wherein said first region comprises metal ions from said second metal layer; and removing said second region from said chalcogenide material."

Dated: September 1, 2005

Respectfully submitted,

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	Effective on 12/08/2004. Fees pursuant to the Consolidated Appropriations Act, 2005 (H.R. 4818).				Complete if Known				
OIB					Application Nun	0/774,515-Cd	774,515-Conf. #8694		
	TEE TRANSMITTAL			Filing Date Fe		ebruary 10, 2004			
SED	_\						John T. Moore		
SEP 0 1 20L	₹ For FY 2005					J. M. Dolan			
	Applicant claims small entity status. See 37 CFR 1.27			Art Unit 28		2813			
PADEMARKO	TAL AMOUNT OF PAYMENT (\$) 1,715.00				Attorney Docket No. M4065.0697/			697-A	
OEMARK	METHOD OF PAYMENT (check all that apply)								
	Check X Credit Card Money Order None Other (please identify):								
	x Deposit Account Deposit Account Number: 04-1073 Deposit Account Name: Dickstein Shapiro Morin & Oshinsky LLP								
	For the above-identified deposit account, the Director is hereby authorized to: (check all that apply)								
	X Charge fee(s) indicated below Charge fee(s) indicated below, except for the filing fee								
	Charge any additional fee(s) or underpayment of fee(s) under 37 CFR 1.16 and 1.17  FEE CALCULATION  1. BASIC FILING, SEARCH, AND EXAMINATION FEES  FILING FEES SEARCH FEES EXAMINATION FEES								
	Application T	ype <u>Fee (</u> \$	Small Entity Fee (\$)	Fee (\$	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	Fees P	aid (\$)
	Utility	300		500	250	200	100	10001	<u> </u>
	Design	200	100	100	50	130	65		
	Plant	200	100	300	150	160	80		
	Reissue	300	150	500	250	600	300		
	Provisional	200	100	0	0	0	0		
	2. EXCESS CL		100	Ů	v	v	Ü		Small Entity
	Fee Description							Fee (\$)	Fee (\$)
	Each claim over 20 (including Reissues) 50 Each independent claim over 3 (including Reissues) 200								25
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	Multiple depend	dent claims						360	180
	Total Claims	tal Claims Extra Claims Fee (\$) Fee Paid (\$) Multiple Depend						ent Claims	
	x =					Fee (\$) Fee Paid (\$)			1
	Indep. Claims 2	Extra Claims	Fee (\$)	Fee F	Paid (\$)				_
	3. APPLICATION SIZE FEE  If the specification and drawings exceed 100 sheets of paper (excluding electronically filed sequence or computer listings under 37 CFR 1.52(e)), the application size fee due is \$250 (\$125 for small entity) for each additional 50 sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s).								
	Total Sheets Extra Sheets Number of each additional 50 or fraction thereof Fee (\$) Fee Paid (\$)  - 100 = /50 (round up to a whole number) x = //  4. OTHER FEE(S) Fees Paid (\$)								<u>'aid (\$)</u>
									Paid (\$)
	Non-English Specification, \$130 fee (no small entity discount)								
	Other (e.g. late filing surcharge). 1501 Utility issue fee 1,400.00								
	1504 Publication fee for early, voluntary, or normal 300.00  8091 Printed copy of patent w/o color 15.00								
	SUBMITTED BY	- A			Registration No.			(000) 00	
	Signature	10			(Attorney/Agent)	28,371	Telephone	(202) 82	8-2232
	Name (Print/Type)	Thomas J. D'Ami			Date	Septembe	r 1, 2005		

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